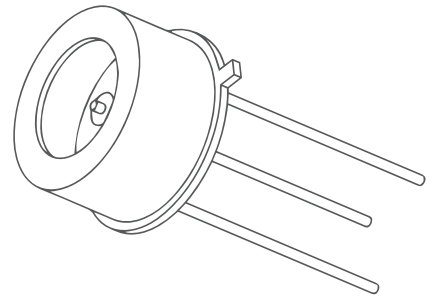


PVIA-5-1×1-TO39-NW-36



InAsSb room temperature optically immersed photovoltaic infrared detector

FEATURES

- Spectral range: 2.6 to 5.3 μm
- RoHS-compliant III-V material
- High ambient operating and storage temperature
- Unique optical immersion technology applied
- Back-side illuminated
- No minimum order quantity required

APPLICATIONS

- Contactless temperature measurement: railway transport, industrial and laboratory processes monitoring
- Flame and explosion detection
- Threat warning systems
- Heat-seeking, thermal signature detection
- Dentistry
- Gas detection, monitoring and analysis: CH_4 , C_2H_2 , CH_2O , HCl , NH_3 , SO_2 , C_2H_6 , CO , CO_2 , NO_x
- Breath analysis: C_2H_6 , CH_2O , NH_3 , NO , OCS
- Gas leak detection
- Combustion process control
- Non-destructive material testing

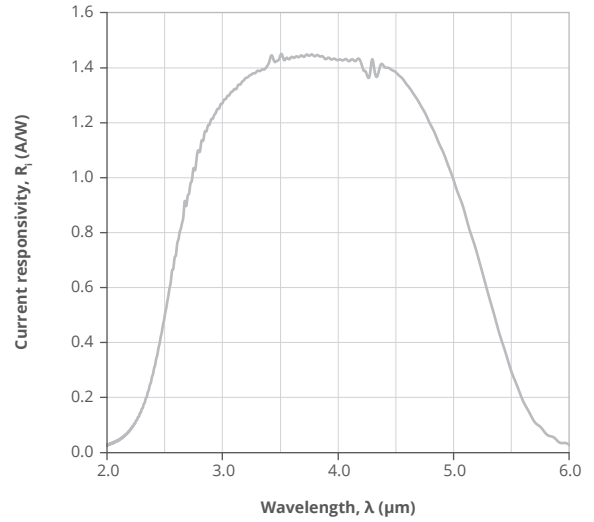
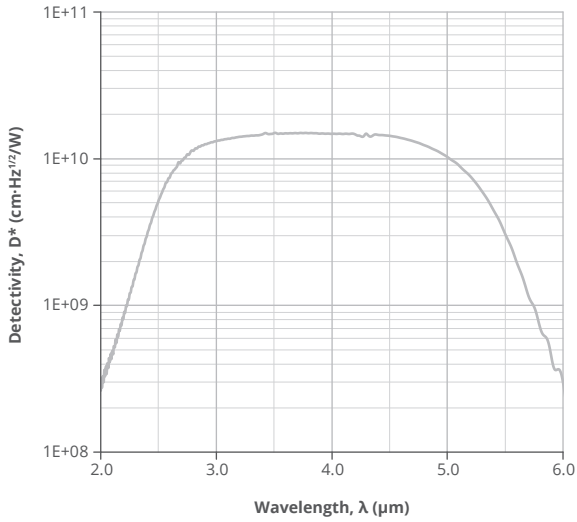
DETECTOR CONFIGURATION

Detector symbol	Cooling	Temperature sensor	Optical area, A_d , mm \times mm	Optical immersion (p. 188)	Package	Acceptance angle, Φ , deg.	Window
PVIA-5-1×1-TO39-NW-36	no	n/a	1×1	hyperhemisphere	TO39 (3 pins)	~36	no

SPECIFICATION ($T_{\text{amb}} = 293 \text{ K}$, $V_b = 0 \text{ V}$)

Detector symbol	Cut-on wavelength (10%)	Peak wavelength	Cut-off wavelength (10%)	Detectivity		Current responsivity		Time constant	Dynamic resistance	
	$\lambda_{\text{cut-on}}$	λ_{peak}	$\lambda_{\text{cut-off}}$	$D^*(\lambda_{\text{peak}}, 20\text{kHz})$		$R_i(\lambda_{\text{peak}})$		τ	R_d	
	μm	μm	μm	cm·Hz ^{1/2} /W		A/W		ns	Ω	
	Typ.	Typ.	Typ.	Min.	Typ.	Min.	Typ.	Typ.	Min.	Typ.
PVIA-5-1×1-TO39-NW-36	2.3	4.0±0.5	5.6	5.0×10 ⁹	1.7×10 ¹⁰	1.2	1.4	30	80	150

SPECTRAL RESPONSE (Typ., $T_{amb} = 293\text{ K}$)



MECHANICAL LAYOUT AND PINOUT

- TO39 (3 pins) package (without window) – Technical drawing (p. 198)

RECOMMENDED AMPLIFIER

- SIP-TO39 series (p. 138)

ABSOLUTE MAXIMUM RATINGS

Parameter	Test conditions/remarks	Value	Unit
Ambient operating temperature, T_{amb}	Detector parameters depend on T_{amb}	-20 to 70	°C
Storage temperature, T_{stg}		-20 to 85	°C
Soldering temperature	Within 5 s or less	≤370	°C
Storage humidity	No dew condensation	10 to 90	%
Maximum incident optical power density	Continuous wave (CW) or single pulses >1 μs duration	2.5	W/cm ²
	Single pulses <1 μs duration	10	kW/cm ²
Maximum bias voltage, $V_{b,max}$		-1	V

Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. Constant or repeated exposure to absolute maximum rating conditions may affect the quality and reliability of the device.